



TSB58T_n100S(A)S-255A

3A/100V⁽¹⁾, low VF Schottky barrier diode with trench MOS structure

ttB10.44 Tm 0 g 0 G [()] TJ E51

Mechanical Data

Chip Drawing	Item	Information	
	Die Size (A)	1473 μ m	58 mil

